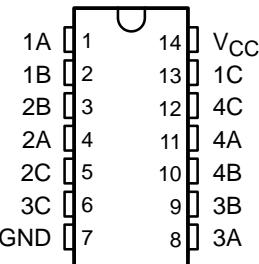


- Wide Operating Voltage Range of 2 V to 6 V
- Typical Switch Enable Time of 18 ns
- Low Power Consumption, 20- μ A Max I_{CC}
- Low Input Current of 1 μ A Max
- High Degree of Linearity
- High On-Off Output-Voltage Ratio
- Low Crosstalk Between Switches
- Low On-State Impedance . . .
50- Ω TYP at $V_{CC} = 6$ V
- Individual Switch Controls

D, DB, N, NS, OR PW PACKAGE
(TOP VIEW)



description/ordering information

The SN74HC4066 is a silicon-gate CMOS quadruple analog switch designed to handle both analog and digital signals. Each switch permits signals with amplitudes of up to 6 V (peak) to be transmitted in either direction.

Each switch section has its own enable input control (C). A high-level voltage applied to C turns on the associated switch section.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

ORDERING INFORMATION

TA	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	PDIP – N	Tube of 25	SN74HC4066N	SN74HC4066N
	SOIC – D	Tube of 50	SN74HC4066D	HC4066
		Reel of 2500	SN74HC4066DR	
		Reel of 250	SN74HC4066DT	
	SOP – NS	Reel of 2000	SN74HC4066NSR	HC4066
	SSOP – DB	Reel of 2000	SN74HC4066DBR	HC4066
	TSSOP – PW	Tube of 90	SN74HC4066PW	HC4066
		Reel of 2000	SN74HC4066PWR	
		Reel of 250	SN74HC4066PWT	

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE (each switch)

INPUT CONTROL (C)	SWITCH
L	OFF
H	ON

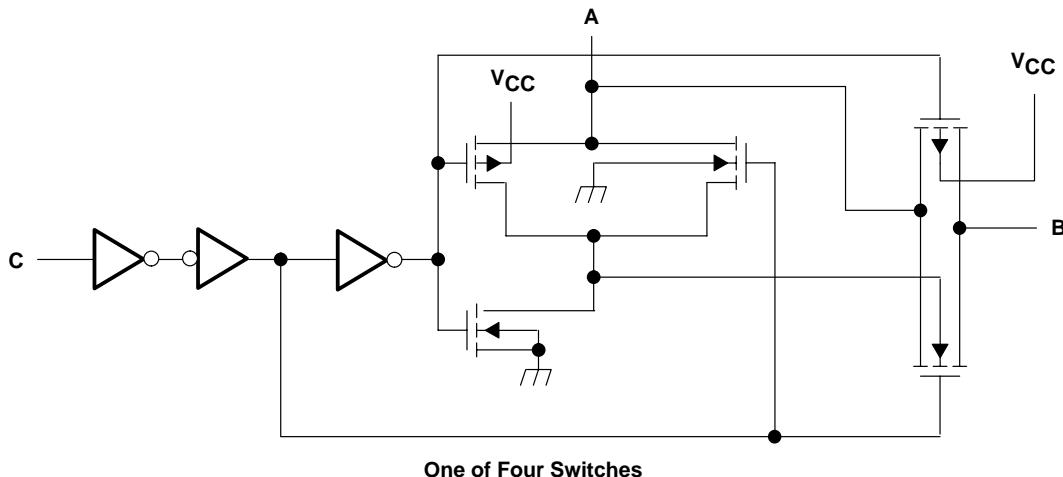


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SN74HC4066 **QUADRUPLE BILATERAL ANALOG SWITCH**

SCLS325G – MARCH 1996 – REVISED JULY 2003

logic diagram, each switch (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to ground unless otherwise specified.

1. All voltages are with respect to ground unless otherwise specified.
2. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 3)

			MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		2†	5	6	V
V _{I/O}	I/O port voltage		0	V _{CC}		V
V _{IH}	High-level input voltage, control inputs		V _{CC} = 2 V	1.5	V _{CC}	V
			V _{CC} = 4.5 V	3.15	V _{CC}	
			V _{CC} = 6 V	4.2	V _{CC}	
V _{IL}	Low-level input voltage, control inputs		V _{CC} = 2 V	0	0.3	V
			V _{CC} = 4.5 V	0	0.9	
			V _{CC} = 6 V	0	1.2	
Δt/Δv	Input transition rise/fall time		V _{CC} = 2 V		1000	ns
			V _{CC} = 4.5 V		500	
			V _{CC} = 6 V		400	
TA	Operating free-air temperature		–40	85	°C	

† With supply voltages at or near 2 V, the analog switch on-state resistance becomes very nonlinear. It is recommended that only digital signals be transmitted at these low supply voltages.

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
r _{on}	On-state switch resistance I _T = –1 mA, V _I = 0 to V _{CC} , V _C = V _{IH} (see Figure 1)	2 V	150			106	Ω	
		4.5 V	50	85				
		6 V	30					
r _{on(p)}	Peak on-state resistance V _I = V _{CC} or GND, V _C = V _{IH} , I _T = –1 mA	2 V	320			215	Ω	
		4.5 V	70	170				
		6 V	50					
I _I	Control input current V _C = 0 or V _{CC}	6 V	±0.1	±100		±1000		nA
I _{soff}	Off-state switch leakage current V _I = V _{CC} or 0, V _O = V _{CC} or 0, V _C = V _{IL} (see Figure 2)	6 V		±0.1		±5		µA
I _{son}	On-state switch leakage current V _I = V _{CC} or 0, V _C = V _{IH} (see Figure 3)	6 V		±0.1		±5		µA
I _{CC}	Supply current V _I = 0 or V _{CC} , I _O = 0	6 V		2		20		µA
C _i	Input capacitance A or B	5 V	9			10	pF	
			3	10				
C _f	Feed-through capacitance A to B	V _I = 0		0.5				pF
C _o	Output capacitance A or B	5 V	9					pF

SN74HC4066

QUADRUPLE BILATERAL ANALOG SWITCH

SCLS325G – MARCH 1996 – REVISED JULY 2003

switching characteristics over recommended operating free-air temperature range

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CC}	T _A = 25°C			MIN	MAX	UNIT
					MIN	TYP	MAX			
t _{PLH} , t _{PHL}	Propagation delay time	A or B	B or A C _L = 50 pF (see Figure 4)	2 V	10	60	75	ns	ns	
				4.5 V	4	12	15			
				6 V	3	10	13			
t _{PZH} , t _{PZL}	Switch turn-on time	C	A or B R _L = 1 kΩ, C _L = 50 pF (see Figure 5)	2 V	70	180	225	ns	ns	
				4.5 V	21	36	45			
				6 V	18	31	38			
t _{PLZ} , t _{PHZ}	Switch turn-off time	C	A or B R _L = 1 kΩ, C _L = 50 pF (see Figure 5)	2 V	50	200	250	ns	ns	
				4.5 V	25	40	50			
				6 V	22	34	43			
f _I	Control input frequency	C	A or B C _L = 15 pF, R _L = 1 kΩ, V _C = V _{CC} or GND, V _O = V _{CC} /2 (see Figure 6)	2 V	15			MHz	MHz	
				4.5 V	30					
				6 V	30					
Control feed-through noise	C	A or B	C _L = 50 pF, R _{in} = R _L = 600 Ω, V _C = V _{CC} or GND, f _{in} = 1 MHz (see Figure 7)	4.5 V	15			mV (rms)	mV (rms)	
				6 V	20					

operating characteristics, V_{CC} = 4.5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TYP	UNIT
C _{pd}	Power dissipation capacitance per gate	C _L = 50 pF,	f = 1 MHz	45	pF
Minimum through bandwidth, A to B or B to A [†]	[20 log (V _O /V _I)] = -3 dB	C _L = 50 pF, V _C = V _{CC}	R _L = 600 Ω, (see Figure 8)	30	MHz
Crosstalk between any switches [‡]		C _L = 10 pF, f _{in} = 1 MHz	R _L = 50 Ω, (see Figure 9)	45	dB
Feed through, switch off, A to B or B to A [‡]		C _L = 50 pF, f _{in} = 1 MHz	R _L = 600 Ω, (see Figure 10)	42	dB
Amplitude distortion rate, A to B or B to A		C _L = 50 pF, f _{in} = 1 kHz	R _L = 10 kΩ, (see Figure 11)	0.05%	

[†] Adjust the input amplitude for output = 0 dBm at f = 1 MHz. Input signal must be a sine wave.

[‡] Adjust the input amplitude for input = 0 dBm at f = 1 MHz. Input signal must be a sine wave.

PARAMETER MEASUREMENT INFORMATION

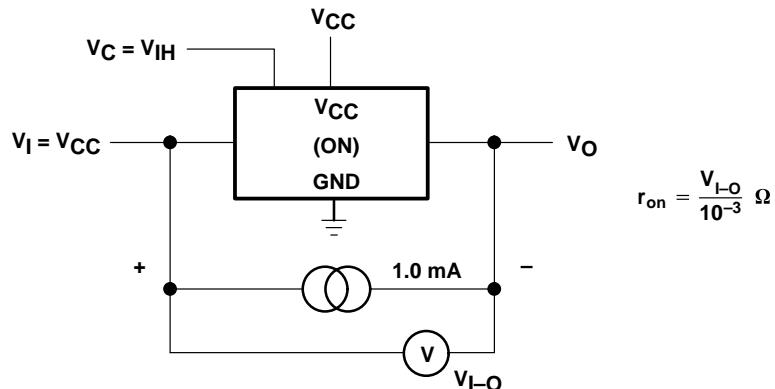


Figure 1. On-State Resistance Test Circuit

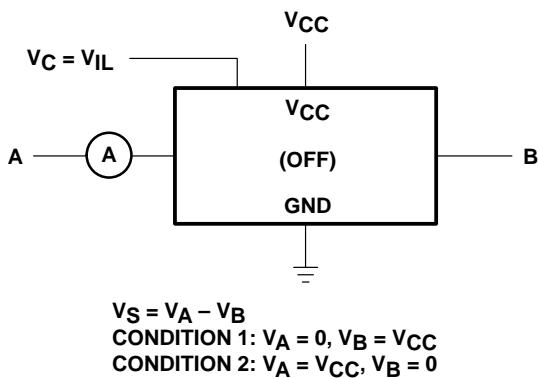


Figure 2. Off-State Switch Leakage-Current Test Circuit

PARAMETER MEASUREMENT INFORMATION

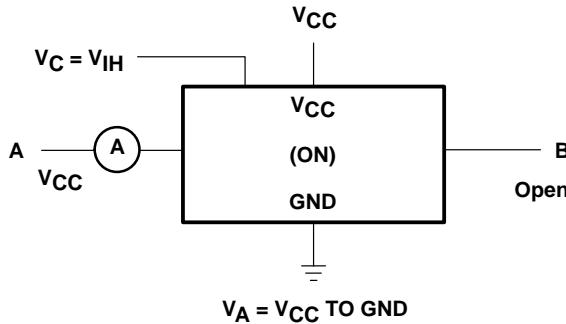


Figure 3. On-State Leakage-Current Test Circuit

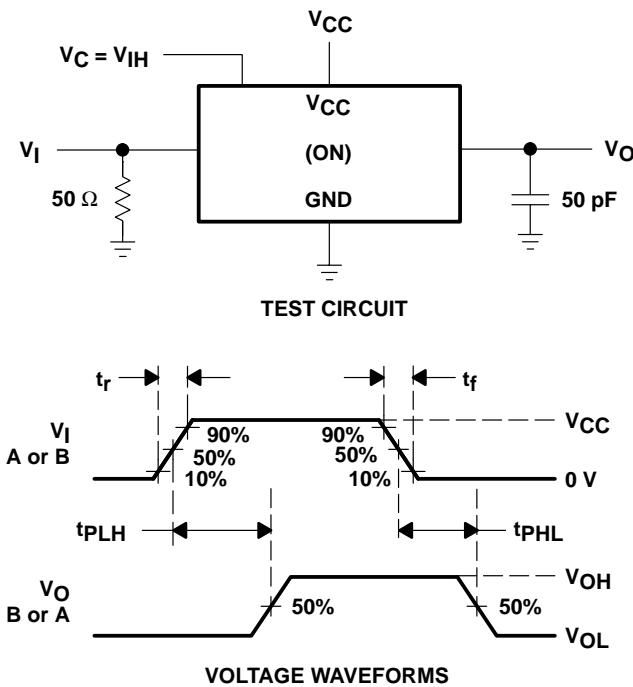
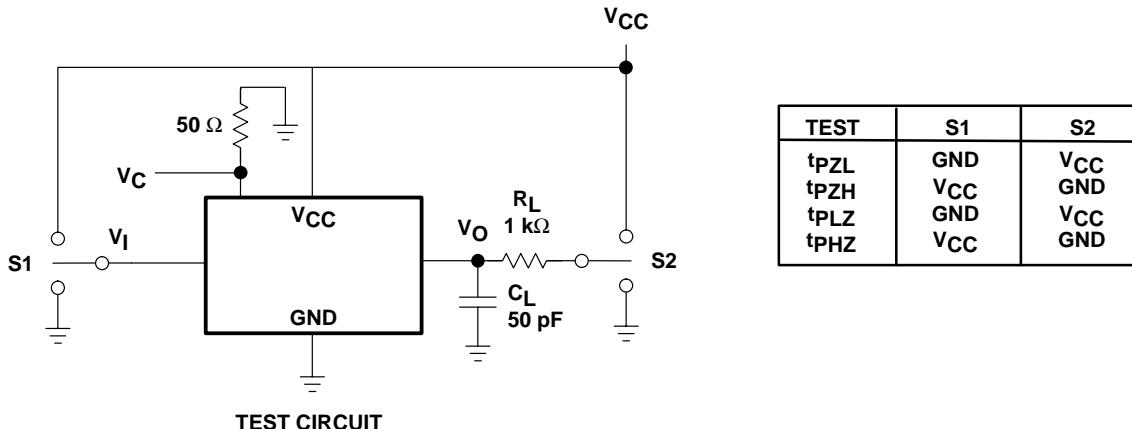
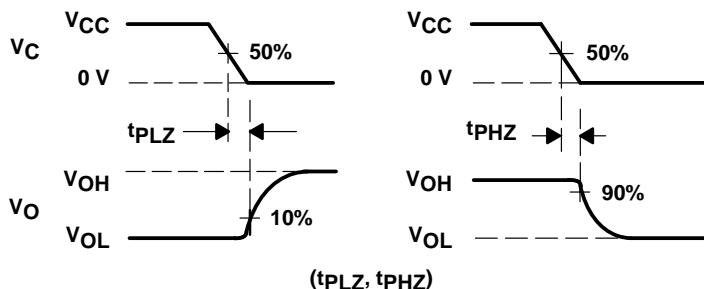
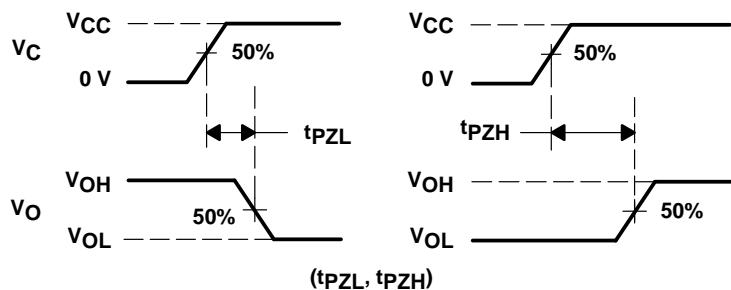


Figure 4. Propagation Delay Time, Signal Input to Signal Output

PARAMETER MEASUREMENT INFORMATION



TEST	S1	S2
t _{PZL}	GND	V _{CC}
t _{PZH}	V _{CC}	GND
t _{PLZ}	GND	V _{CC}
t _{PHZ}	V _{CC}	GND



VOLTAGE WAVEFORMS

Figure 5. Switching Time (t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}), Control to Signal Output

PARAMETER MEASUREMENT INFORMATION

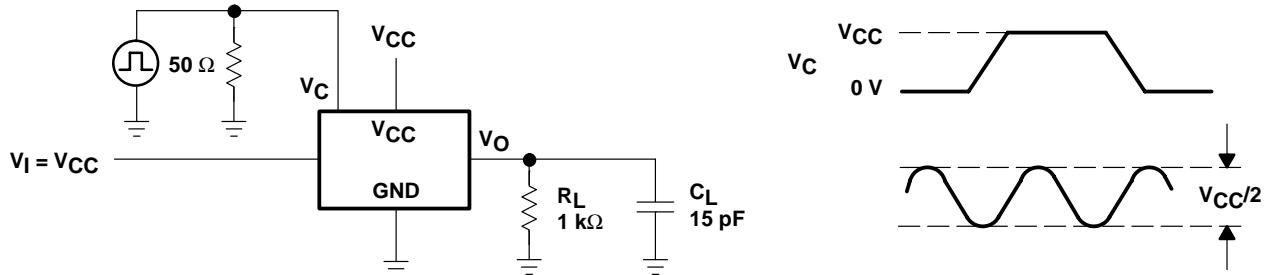


Figure 6. Control-Input Frequency

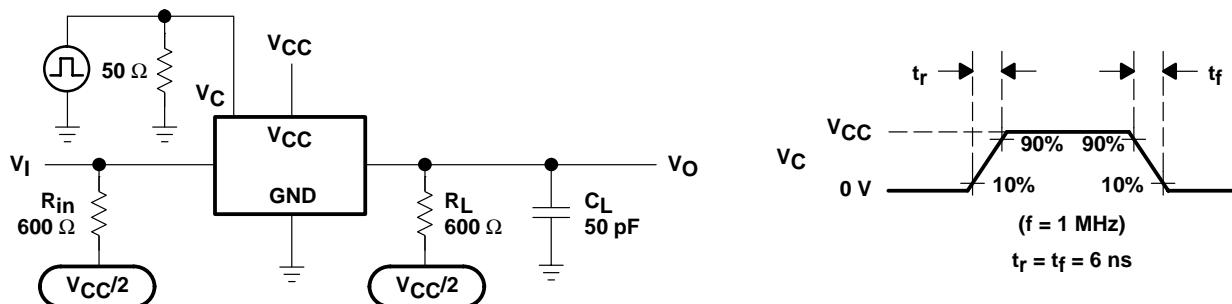


Figure 7. Control Feed-Through Noise

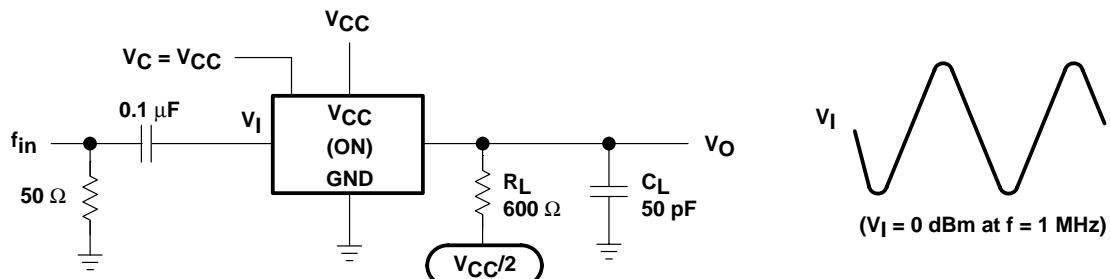


Figure 8. Minimum Through Bandwidth

PARAMETER MEASUREMENT INFORMATION

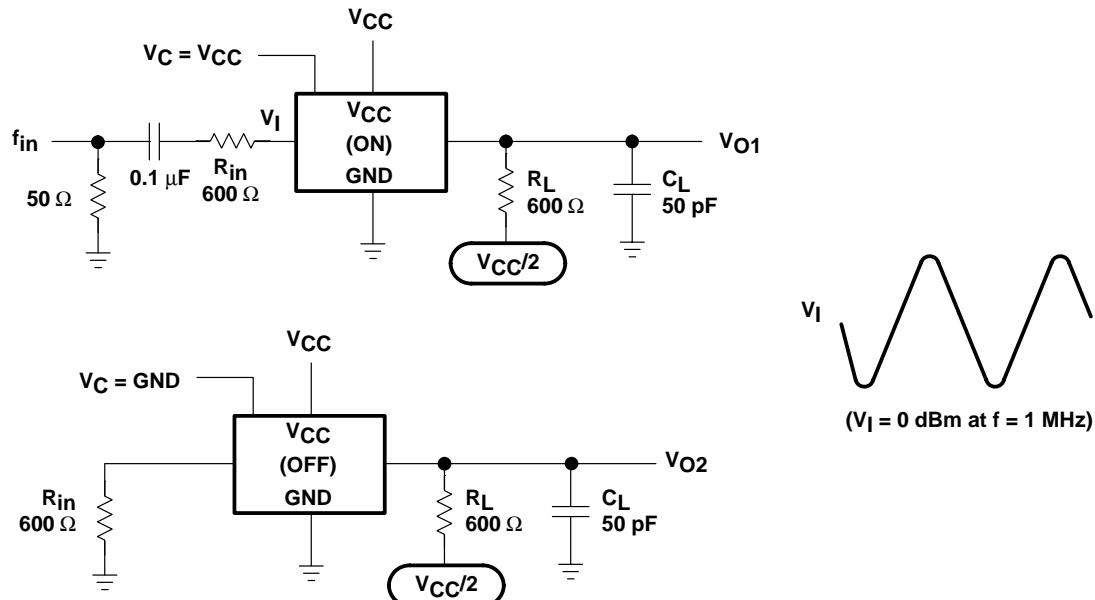


Figure 9. Crosstalk Between Any Two Switches

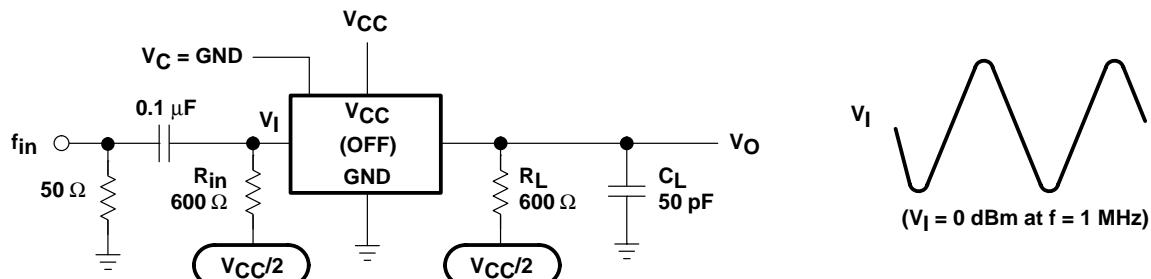


Figure 10. Feed Through, Switch Off

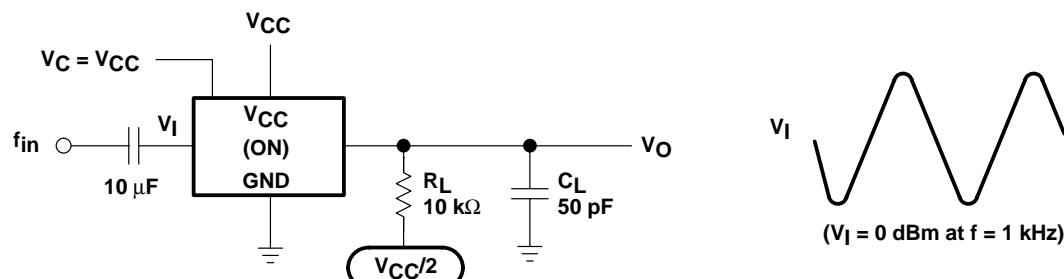


Figure 11. Amplitude-Distortion Rate

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74HC4066D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066DBLE	OBsolete	SSOP	DB	14		TBD	Call TI	Call TI	-40 to 85		
SN74HC4066DBR	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066DBRE4	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066DRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066DT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066N	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC4066N	Samples
SN74HC4066NE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC4066N	Samples
SN74HC4066NSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066PW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066PWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066PWLE	OBsolete	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 85		
SN74HC4066PWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066PWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples
SN74HC4066PWT	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC4066	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

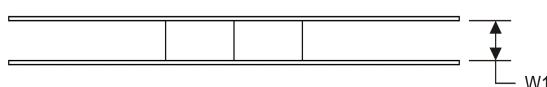
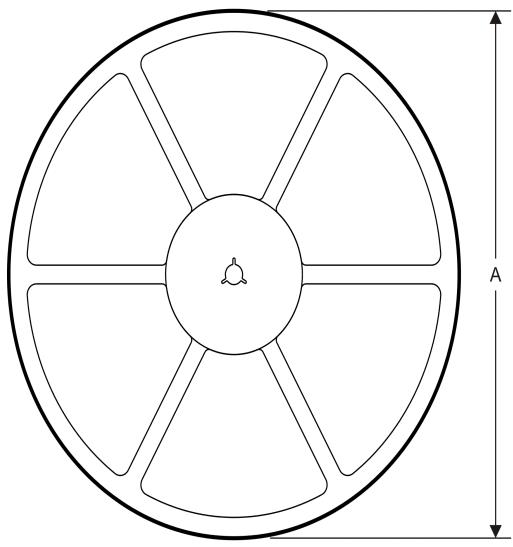
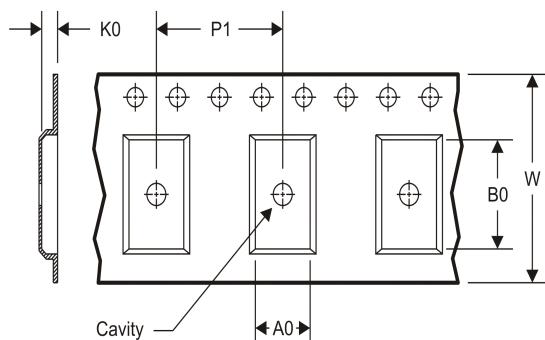
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC4066DBR	SSOP	DB	14	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN74HC4066DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC4066DT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC4066NSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74HC4066PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC4066PWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC4066DBR	SSOP	DB	14	2000	367.0	367.0	38.0
SN74HC4066DR	SOIC	D	14	2500	367.0	367.0	38.0
SN74HC4066DT	SOIC	D	14	250	367.0	367.0	38.0
SN74HC4066NSR	SO	NS	14	2000	367.0	367.0	38.0
SN74HC4066PWR	TSSOP	PW	14	2000	367.0	367.0	35.0
SN74HC4066PWT	TSSOP	PW	14	250	367.0	367.0	35.0

N (R-PDIP-T**)

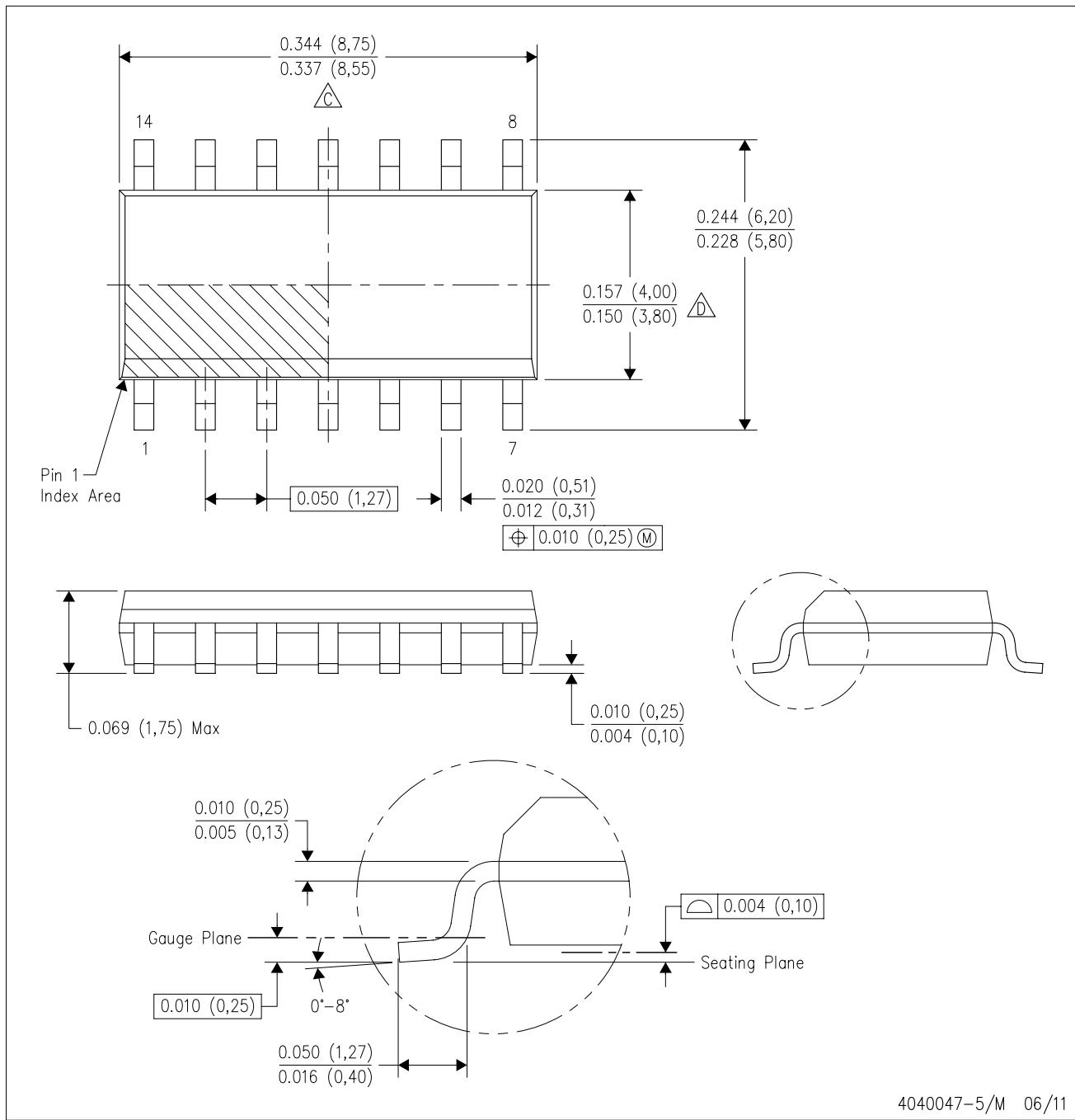
16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

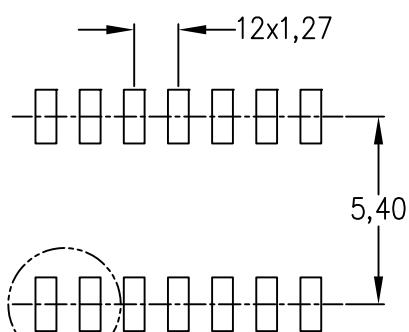
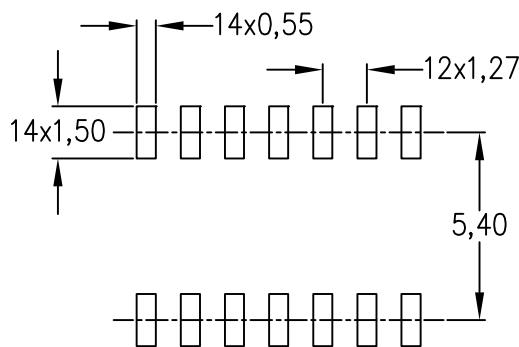
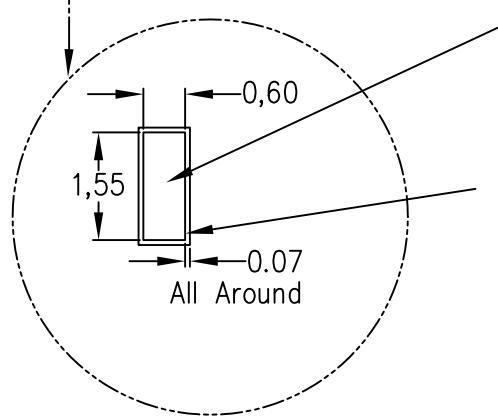
C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0.15) each side.

D Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0.43) each side.

E Reference JEDEC MS-012 variation AB.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE

Example Board Layout
(Note C)Stencil Openings
(Note D)Example
Non Soldermask Defined PadExample
Pad Geometry
(See Note C)Example
Solder Mask Opening
(See Note E)

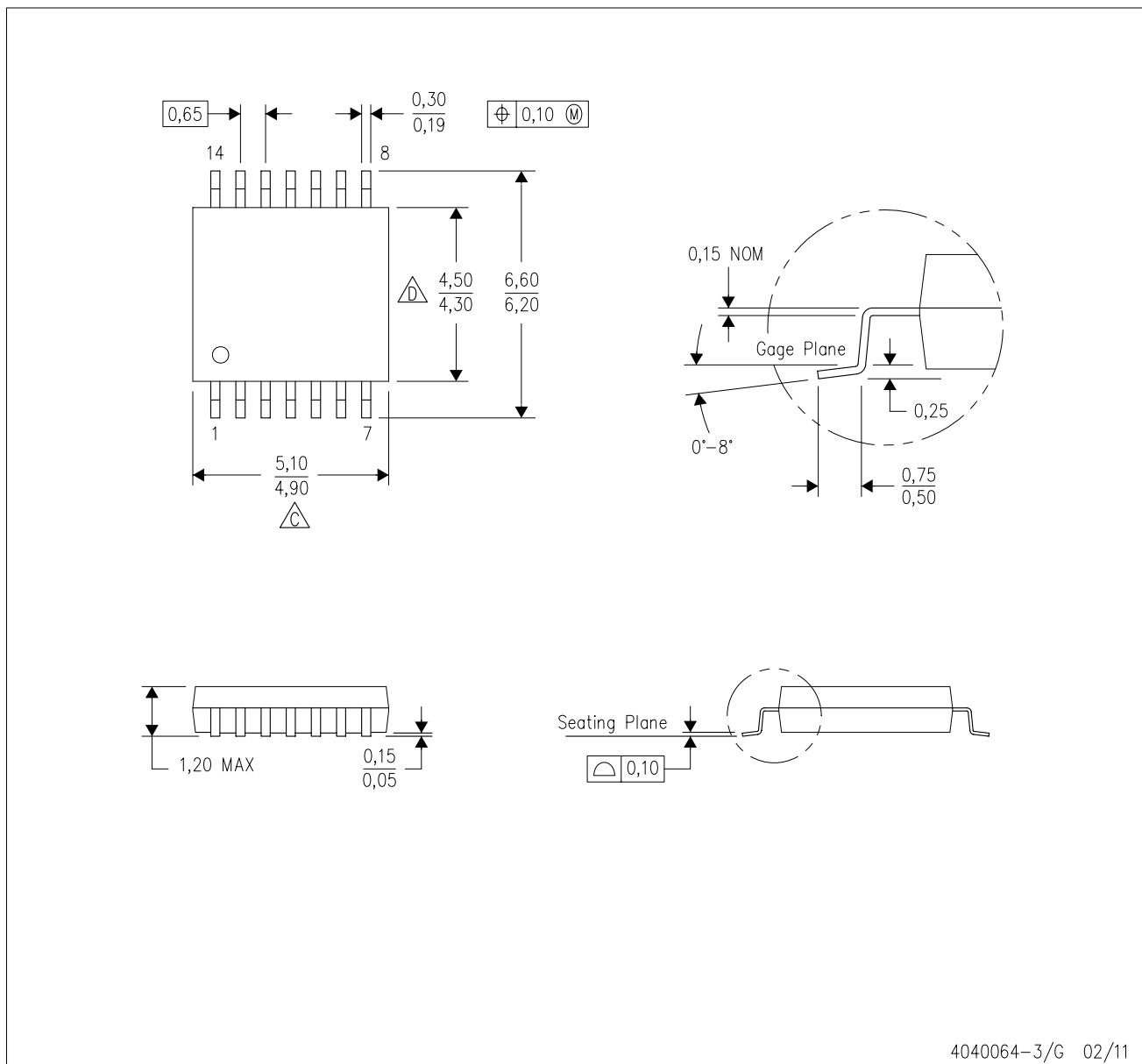
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NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Publication IPC-7351 is recommended for alternate designs.
- Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4040064-3/G 02/11

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

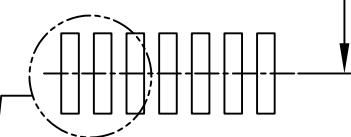
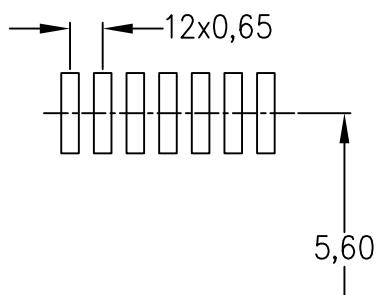
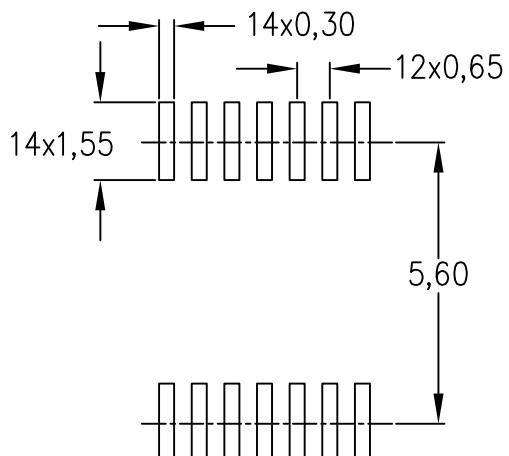
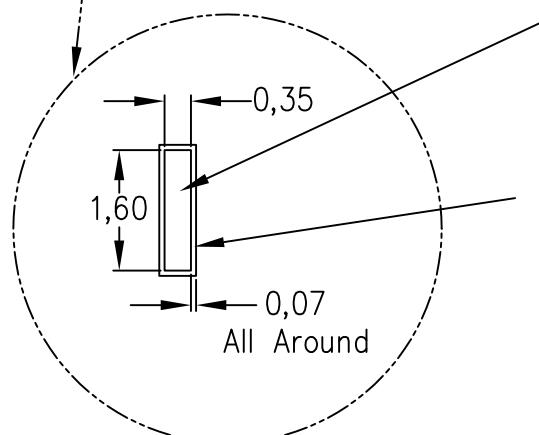
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE

Example Board Layout
(Note C)Stencil Openings
(Note D)Example
Non Soldermask Defined PadExample
Pad Geometry
(See Note C)Example
Solder Mask Opening
(See Note E)

4211284-2/F 12/12

NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Publication IPC-7351 is recommended for alternate designs.
- Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

MECHANICAL DATA

NS (R-PDSO-G)**

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



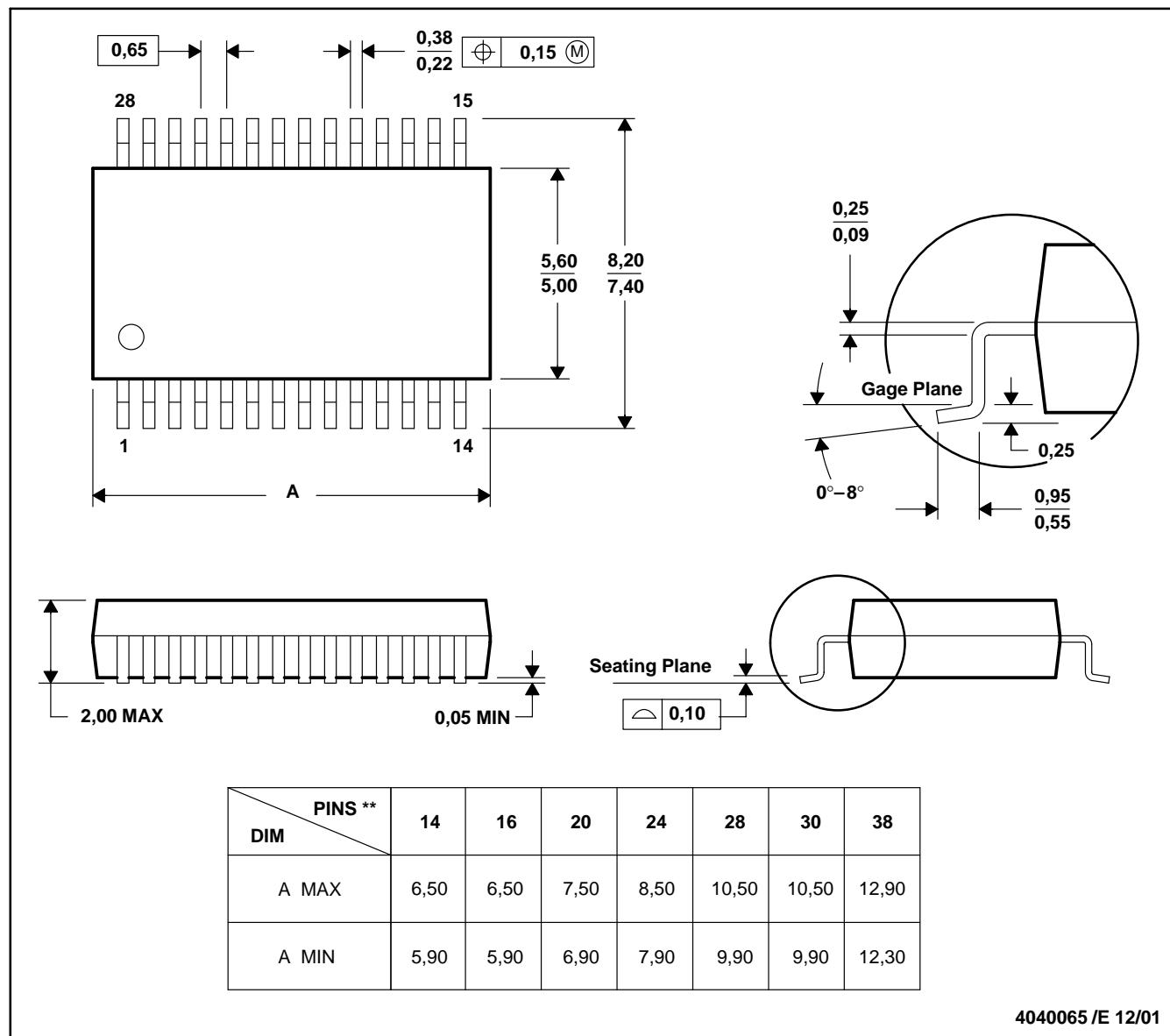
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-150

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